SILICON POWER TRANSISTOR 2SC4552

NPN SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SC4552 is a power transistor developed for high-speed switching and features low $V_{CE(sat)}$ and high hFE. This transistor is ideal for use in drivers such as DC/DC converters and actuators.

In addition, a small resin-molded insulation type package contributes to high-density mounting and reduction of mounting cost.

FEATURES

NEC

- High hFE and low VCE(sat): hFE \geq 100 (VCE = 2 V, IC = 3 A) VCE(sat) \leq 0.3 V (IC = 8 A, IB = 0.4 A)
- Mold package that does not require an insulating board or insulation bushing

•		
Symbol	Ratings	Unit
Vсво	100	V
Vceo	60	V
Vebo	7.0	V
IC(DC)	15	А
C(pulse)*	30	А
IB(DC)	7.5	А
P⊤ (Tc = 25°C)	30	W
P⊤ (Ta = 25°C)	2.0	W
Tj	150	°C
Tstg	–55 to +150	°C
	Vсво Vсео Vсво Ic(DC) Ic(pulse)* IB(DC) Рт (Tc = 25°C) Рт (Ta = 25°C) Tj	VCBO 100 VCEO 60 VEBO 7.0 Ic(DC) 15 Ic(pulse)* 30 IB(DC) 7.5 PT (Tc = 25°C) 30 PT (Ta = 25°C) 2.0 T _j 150

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

* PW \leq 300 μ s, duty cycle \leq 10%

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version. Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

10.0 ± 0.3 \$3.2±0.2 2.7 ±0.2 ÷ + 15.0 ± 0.3 0 ± 0.2 2 0.7 ± 0.1 1.3.0.2 0.65 ± 0.1 2.5 ± 0.1 1.5.1.0.2 2.54 TYP 2.54 TYP Electrode Connection 1 Base 2. Collector 3. Emitter

PACKAGE DRAWING (UNIT: mm)

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

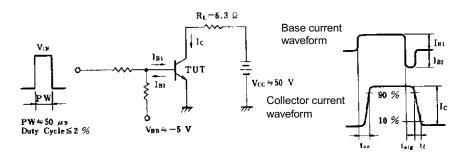
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	VCEO(SUS)	Ic = 8.0 A, I _B = 0.8 A, L = 1 mH	60			V
Collector to emitter voltage	VCEX(SUS)	Ic = 8.0 A, I _{B1} = $-I_{B2}$ = 0.8 A, V _{BE(OFF)} = -1.5 V, L = 180 μ H, clamped	60			V
Collector cutoff current	Ісво	$V_{CB} = 60 \text{ V}, \text{ I}_{E} = 0$			10	μA
Collector cutoff current	ICER	$V_{CE} = 60 \text{ V}, \text{ R}_{BE} = 50 \Omega, \text{ Ta} = 125^{\circ}\text{C}$			1.0	mA
Collector cutoff current	ICEX1	Vce = 60 V, VBE(OFF) = -1.5 V			10	μA
Collector cutoff current	ICEX2	$V_{CE} = 60 \text{ V}, \text{ V}_{BE(OFF)} = -1.5 \text{ V},$ Ta = 125°C			1.0	mA
Emitter cutoff current	Іево	V _{EB} = 5.0 V, Ic = 0			10	μA
DC current gain	hfe1*	Vce = 2.0 V, lc = 1.5 A	100			
DC current gain	hfe2*	Vce = 2.0 V, Ic = 3.0 A	100		400	
DC current gain	hfe3*	Vce = 2.0 V, Ic = 8.0 A	60			
Collector saturation voltage	V _{CE(sat)1} *	Ic = 8.0 A, I _B = 0.4 A			0.3	V
Collector saturation voltage	VCE(sat)2*	Ic = 12 A, I _B = 0.6 A			0.5	v
Base saturation voltage	V _{BE(sat)1} *	Ic = 8.0 A, I _B = 0.4 A			1.2	v
Base saturation voltage	VBE(sat)2*	Ic = 12 A, I _B = 0.6 A			1.5	v
Collector capacitance	Cob	$V_{CB} = 10 V$, $I_E = 0$, $f = 1.0 MHz$		180		pF
Gain bandwidth product	f⊤	Vce = 10 V, Ic = 1.5 A		120		MHz
Turn-on time	ton	$I_{C} = 8.0 \text{ A}, \text{ R}_{L} = 6.3 \Omega,$			0.3	μs
Storage time	tstg	$I_{B1} = -I_{B2} = 0.4 \text{ A}, \text{ Vcc} \cong 50 \text{ V}$ Refer to the test circuit.			1.5	μs
Fall time	tr				0.3	μs

* Pulse test PW \leq 350 μ s, duty cycle \leq 2%

hfe CLASSIFICATION

Marking	М	L	к
hFE2	100 to 200	150 to 300	200 to 400

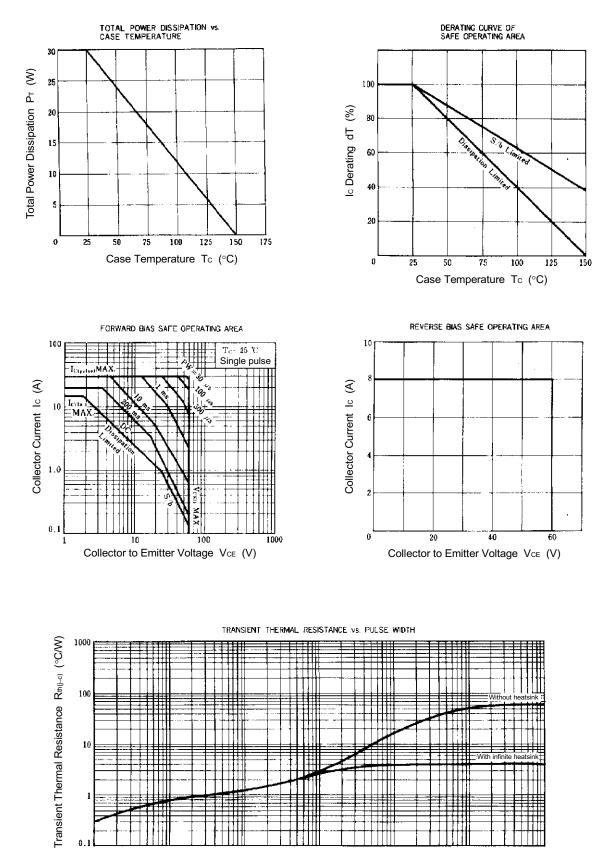
SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT



TYPICAL CHARACTERISTICS (Ta = 25°C)

0.1 0.001

0.01



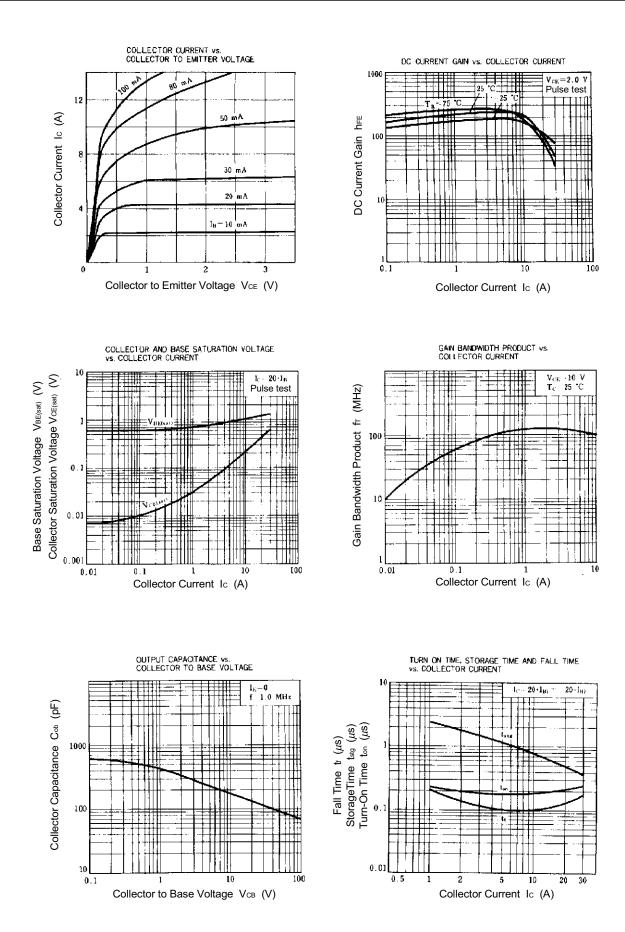
1 Pulse Width PW (s)

10

100

1000

0.1



[MEMO]

- The information in this document is current as of July, 2001. The information is subject to change
 without notice. For actual design-in, refer to the latest publications of NEC's data sheets or data
 books, etc., for the most up-to-date specifications of NEC semiconductor products. Not all products
 and/or types are available in every country. Please check with an NEC sales representative for
 availability and additional information.
- No part of this document may be copied or reproduced in any form or by any means without prior written consent of NEC. NEC assumes no responsibility for any errors that may appear in this document.
- NEC does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from the use of NEC semiconductor products listed in this document or any other liability arising from the use of such products. No license, express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative
 purposes in semiconductor product operation and application examples. The incorporation of these
 circuits, software and information in the design of customer's equipment shall be done under the full
 responsibility of customer. NEC assumes no responsibility for any losses incurred by customers or third
 parties arising from the use of these circuits, software and information.
- While NEC endeavours to enhance the quality, reliability and safety of NEC semiconductor products, customers
 agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize
 risks of damage to property or injury (including death) to persons arising from defects in NEC
 semiconductor products, customers must incorporate sufficient safety measures in their design, such as
 redundancy, fire-containment, and anti-failure features.
- NEC semiconductor products are classified into the following three quality grades:
 "Standard", "Special" and "Specific". The "Specific" quality grade applies only to semiconductor products
 developed based on a customer-designated "quality assurance program" for a specific application. The
 recommended applications of a semiconductor product depend on its quality grade, as indicated below.
 Customers must check the quality grade of each semiconductor product before using it in a particular
 application.
 - "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
 - "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
 - "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC semiconductor products is "Standard" unless otherwise expressly specified in NEC's data sheets or data books, etc. If customers wish to use NEC semiconductor products in applications not intended by NEC, they must contact an NEC sales representative in advance to determine NEC's willingness to support a given application.

(Note)

- (1) "NEC" as used in this statement means NEC Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC semiconductor products" means any semiconductor product developed or manufactured by or for NEC (as defined above).

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.